



SANYO Semiconductors

DATA SHEET

N-channel Silicon Junction FET

TF202FC — Electret Condenser Microphone Applications

Features

- Ultrasmall package facilitates miniaturization in end products.
- Especially suited for use in electret condenser microphone for audio equipments and telephones.
- Excellent voltage characteristics.
- Excellent transient characteristics.
- Adoption of FBET process.
- Halogen free compliance.

Specifications

Absolute Maximum Ratings at $T_a=25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Gate-to-Drain Voltage	V_{GDO}		-20	V
Gate Current	I_G		10	mA
Drain Current	I_D		1	mA
Allowable Power Dissipation	P_D		100	mW
Junction Temperature	T_j		150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics at $T_a=25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gate-to-Drain Breakdown Voltage	$V_{(BR)GDO}$	$I_G=-100\mu\text{A}$	-20			V
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=5\text{V}, I_D=1\mu\text{A}$	-0.2	-0.6	-1.0	V

Marking : E

Continued on next page.

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TF202FC

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain Current	I_{DSS}	$V_{DS}=5V, V_{GS}=0V$	140*		350*	μA
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=5V, V_{GS}=0V, f=1kHz$	0.5	1.0		mS
Input Capacitance	C_{iss}	$V_{DS}=5V, V_{GS}=0V, f=1MHz$		3.5		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=5V, V_{GS}=0V, f=1MHz$		0.65		pF
[Ta=25°C, VCC=4.5V, RL=1kΩ, Cin=15pF, See specified Test Circuit.]						
Voltage Gain	G_V	$V_{IN}=10mV, f=1kHz$		-3.0		dB
Reduced Voltage Characteristic	ΔG_{VV}	$V_{IN}=10mV, f=1kHz, V_{CC}=4.5V \rightarrow 1.5V$		-1.2	-3.5	dB
Frequency Characteristic	ΔG_{vf}	$f=1kHz$ to 110Hz			-1.0	dB
Total Harmonic Distortion	THD	$V_{IN}=30mV, f=1kHz$		1.2		%
Output Noise Voltage	V_{NO}	$V_{IN}=0V, A$ Curve			-110	dB

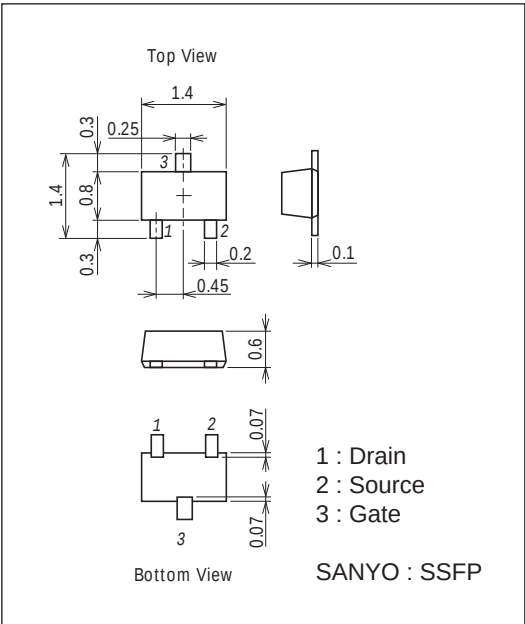
* : The TF202FC is classified by I_{DSS} as follows : (unit : μA)

Rank	4	5
I_{DSS}	140 to 240	210 to 350

Package Dimensions

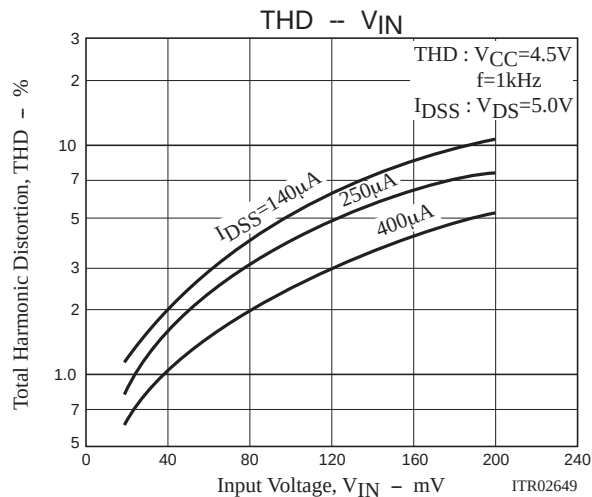
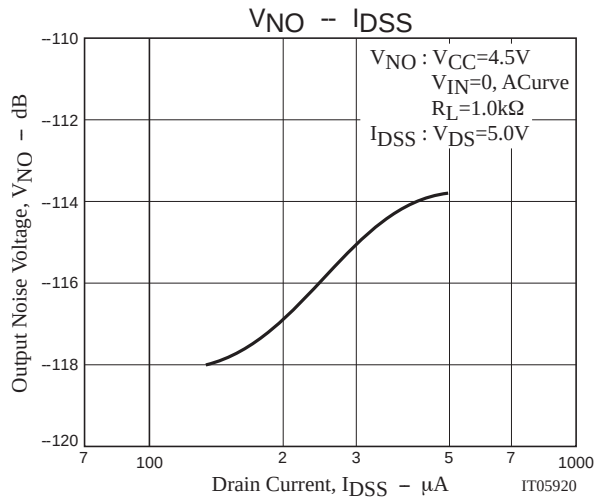
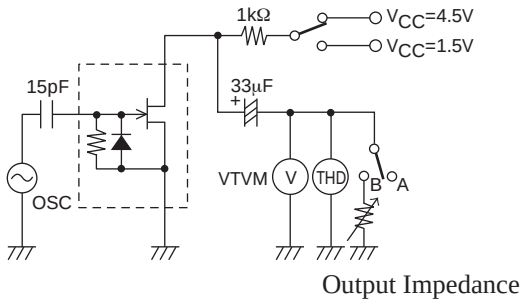
unit : mm (typ)

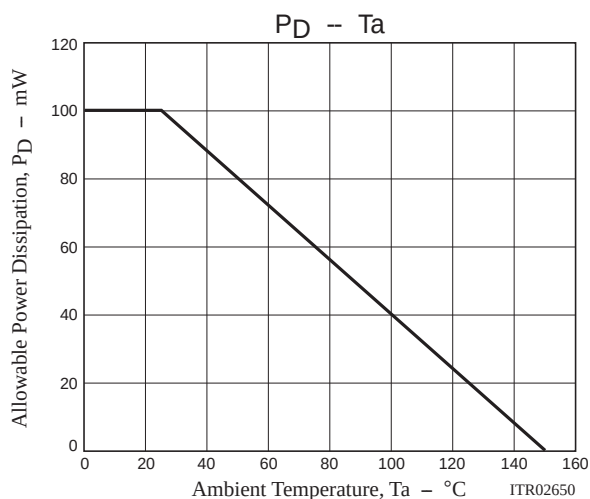
7029-004



Test Circuit

Voltage gain
Frequency Characteristic
Distortion
Reduced Voltage Characteristic





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